



Bulletin I2776 rev. D 09/97

## P400 SERIES

### PASSIVATED ASSEMBLED CIRCUIT ELEMENTS

#### Features

- Glass passivated junctions for greater reliability
- Electrically isolated base plate
- Available up to 1200 V<sub>RRM</sub>, V<sub>DRM</sub>
- High dynamic characteristics
- Wide choice of circuit configurations
- Simplified mechanical design and assembly
- UL E78996 approved 

40A

#### Description

The P400 series of Integrated Power Circuits consists of power thyristors and power diodes configured in a single package. With its isolating base plate, mechanical designs are greatly simplified giving advantages of cost reduction and reduced size.

Applications include power supplies, control circuits and battery chargers.

#### Major Ratings and Characteristics

Parameters	P400	Units
I <sub>D</sub>	40	A
@ T <sub>C</sub>	80	°C
I <sub>FSM</sub>	385	A
@ 60Hz	400	A
I <sup>2</sup> t	745	A <sup>2</sup> s
@ 60Hz	680	A <sup>2</sup> s
I <sup>2</sup> /t	7450	A <sup>2</sup> /s
V <sub>RRM</sub>	400 to 1200	V
V <sub>INS</sub>	2500	V
T <sub>J</sub>	- 40 to 125	°C

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International  
**IR** Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	$V_{RRM}$ maximum repetitive peak reverse voltage V	$V_{RSM}$ maximum non-repetitive peak reverse voltage V	$V_{DRM}$ maximum repetitive peak off-state voltage V	$I_{RRM}$ max. @ $T_J$ max. mA
P401, P421, P431	400	500	400	10
P402, P422, P432	600	700	600	
P403, P423, P433	800	900	800	
P404, P424, P434	1000	1100	1000	
P405, P425, P435	1200	1300	1200	

#### On-state Conduction

Parameter	P400	Units	Conditions					
$I_D$ Maximum DC output current	40	A	$@ T_C = 80^\circ\text{C}$ , full bridge circuits					
$I_{TSM}$ Max. peak one-cycle $I_{FSM}$ non-repetitive on-state or forward current	385	A	$t = 10\text{ms}$	No voltage	100% $V_{RRM}$ reapplied	Sinusoidal half wave, Initial $T_J = T_J$ max.		
	400		$t = 8.3\text{ms}$	reapplied				
	325		$t = 10\text{ms}$	100% $V_{RRM}$				
	340		$t = 8.3\text{ms}$	reapplied				
$I^2t$ Maximum $I^2t$ for fusing	745	$\text{A}^2\text{s}$	$t = 10\text{ms}$	No voltage	100% $V_{RRM}$ reapplied	Initial $T_J = T_J$ max.		
	680		$t = 8.3\text{ms}$	reapplied				
	530		$t = 10\text{ms}$	100% $V_{RRM}$				
	480		$t = 8.3\text{ms}$	reapplied				
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	7450	$\text{A}^2\sqrt{\text{s}}$	$t = 0.1$ to $10\text{ms}$ , no voltage reapplied $I^2t$ for time $tx = I^2\sqrt{t} \cdot \sqrt{tx}$					
$V_{T(TO)1}$ Low value of threshold voltage	0.83	V	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ max.					
$V_{T(TO)2}$ High value of threshold voltage	1.03		$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ max.					
$r_{t1}$ Low level value of on-state slope resistance	9.61	$\text{m}\Omega$	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ max.					
$r_{t2}$ High level value of on-state slope resistance	7.01		$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ max.					
$V_{TM}$ Max. peak on-state or $V_{FM}$ forward voltage drop	1.4	V	$T_J = 25^\circ\text{C}$ , $I_{TM} = \pi \times I_{T(AV)}$ $T_J = 25^\circ\text{C}$ , $I_{TM} = \pi \times I_{F(AV)}$					
$di/dt$ Maximum non repetitive rate of rise of turned on current	200	$\text{A}/\mu\text{s}$	$T_J = 125^\circ\text{C}$ from $0.67 V_{DRM}$ $I_{TM} = \pi \times I_{T(AV)}$ , $I_g = 500\text{mA}$ , $tr < 0.5\mu\text{s}$ , $tp > 6\mu\text{s}$					
$I_H$ Maximum holding current	130	mA	$T_J = 25^\circ\text{C}$ anode supply = 6V, resistive load					
$I_L$ Maximum latching current	250	mA	$T_J = 25^\circ\text{C}$ anode supply = 6V, resistive load					

Blocking

Parameter	P400	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	200	V/μs	$T_J = 125^\circ\text{C}$ , exponential to 0.67 $V_{\text{DRM}}$ gate open
$I_{\text{RRM}}$ Max. peak reverse and off-state leakage current at $V_{\text{RRM}}$ , $V_{\text{DRM}}$	10	mA	$T_J = 125^\circ\text{C}$ , gate open circuit
$I_{\text{RRM}}$ Max peak reverse leakage current	100	μA	$T_J = 25^\circ\text{C}$
$V_{\text{INS}}$ RMS isolation voltage	2500	V	50Hz, circuit to base, all terminal shorted, $T_J = 25^\circ\text{C}$ , $t = 1\text{s}$

Triggering

Parameter	P400	Units	Conditions
$P_{\text{GM}}$ Maximum peak gate power	8	W	
$P_{\text{G(AV)}}$ Maximum average gate power	2		
$I_{\text{GM}}$ Maximum peak gate current	2	A	
- $V_{\text{GM}}$ Maximum peak negative gate voltage	10		
$V_{\text{GT}}$ Maximum gate voltage required to trigger	3 2 1	V	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ Anode Supply = 6V resistive load
$I_{\text{GD}}$ Maximum gate current required to trigger	90 60 35	mA	$T_J = -40^\circ\text{C}$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$ Anode Supply = 6V resistive load
$V_{\text{GD}}$ Maximum gate voltage that will not trigger	0.2	V	$T_J = 125^\circ\text{C}$ , rated $V_{\text{DRM}}$ applied
$I_{\text{GD}}$ Maximum gate current that will not trigger	2	mA	$T_J = 125^\circ\text{C}$ , rated $V_{\text{DRM}}$ applied

Thermal and Mechanical Specification

Parameter	P400	Units	Conditions
$T_J$ Max. operating temperature range	-40 to 125	°C	
$T_{\text{stg}}$ Max. storage temperature range	-40 to 125		
$R_{\text{thJC}}$ Max. thermal resistance, junction to case	1.05	K/W	DC operation per junction
$R_{\text{thCS}}$ Max. thermal resistance, case to heatsink	0.10	K/W	Mounting surface, smooth and greased
T Mounting torque, base to heatsink	4	Nm	A mounting compound is recommended and the torque should be checked after a period of 3 hours to allow for the spread of the compound
wt Approximate weight	58 (2.0)	g (oz)	

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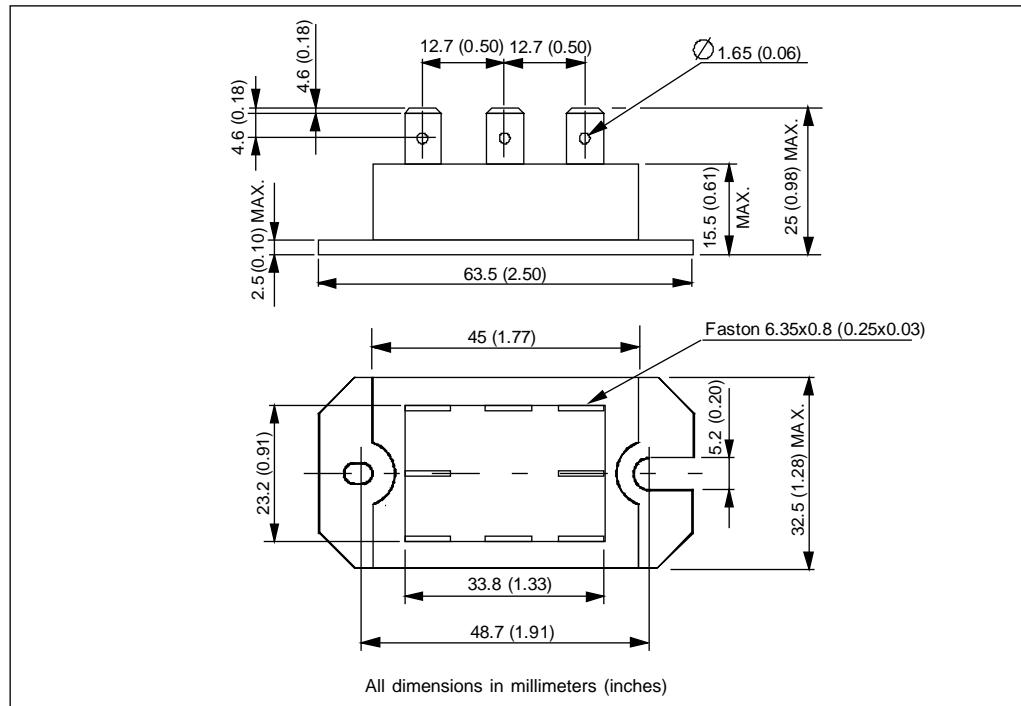
International  
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### Circuit Type and Coding \*

	Circuit "0"	Circuit "2"	Circuit "3"
Terminal Positions			
Schematicdiagram diagram			
	SinglePhase HybridBridge CommonCathode	SinglePhase HybridBridge Doubler	SinglePhase AllSCR Bridge
Basic series	P40.	P42.	P43.
With voltage suppression	P40.K	P42.K	P43.K
With free-wheeling diode	P40.W	-	-
With both voltage suppression and free-wheeling diode	P40.KW	-	-

\* To complete code refer to voltage ratings table, i.e.: for 600V P410.W complete code is P402W

### Outline Table



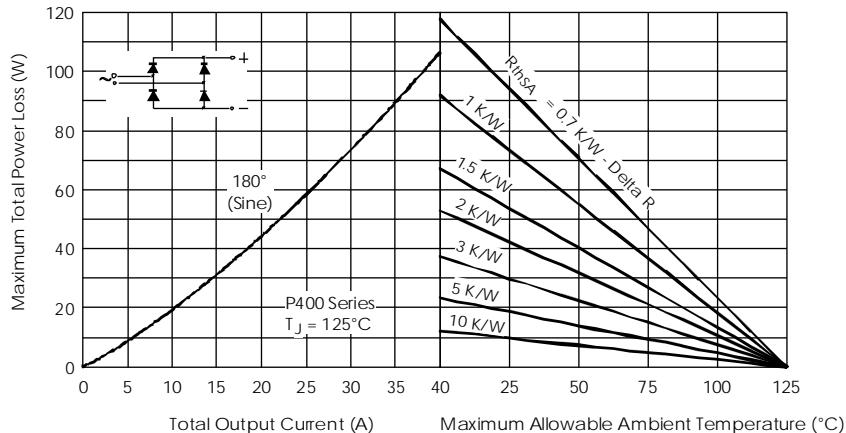


Fig. 1 - Current Ratings Nomogram (1 Module Per Heatsink)

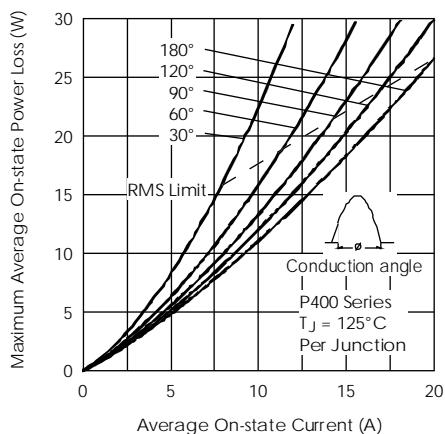


Fig. 2 - On-state Power Loss Characteristics

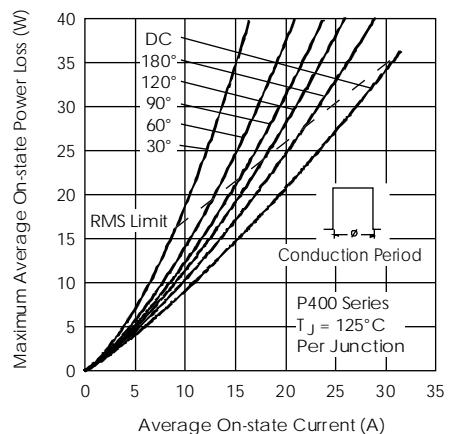


Fig. 3 - On-state Power Loss Characteristics

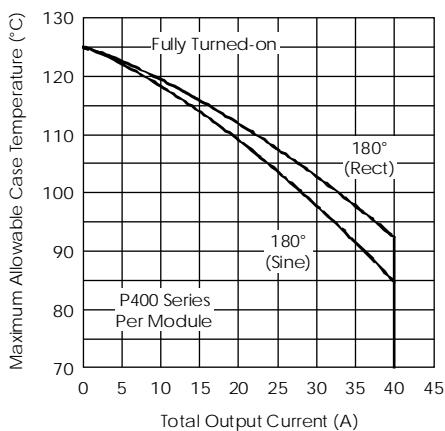


Fig. 4 - Current Ratings Characteristics

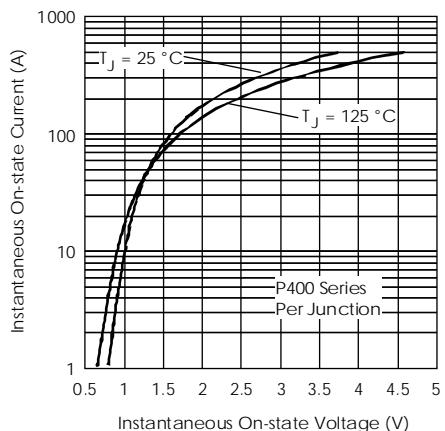


Fig. 5 - On-state Voltage Drop Characteristics

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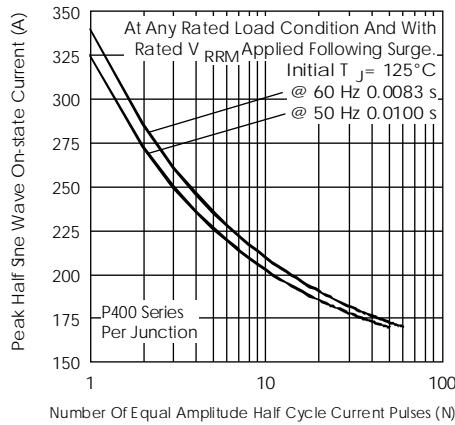


Fig.6-Maximum Non-Repetitive Surge Current

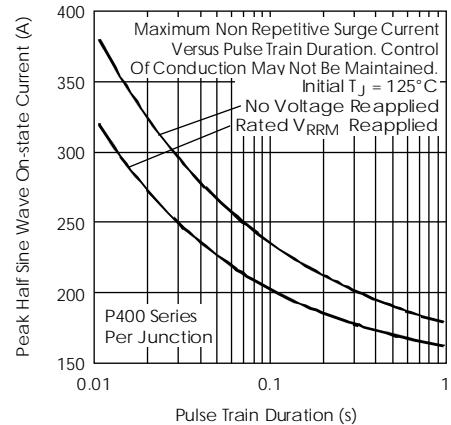


Fig.7-Maximum Non-Repetitive Surge Current

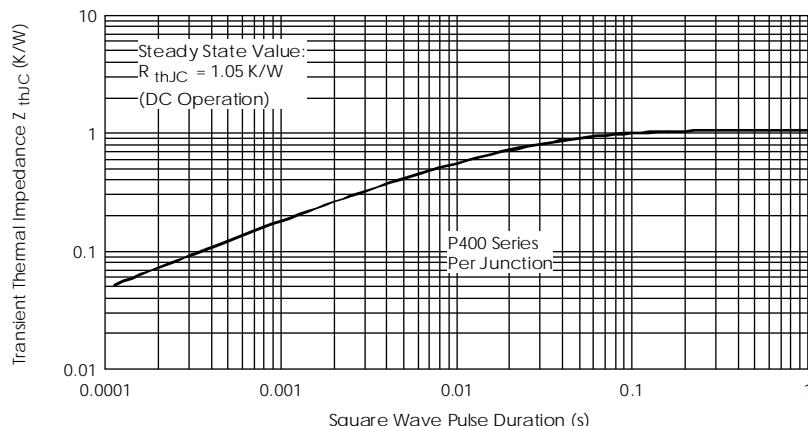


Fig.8-Thermal Impedance  $Z_{thJC}$  Characteristics

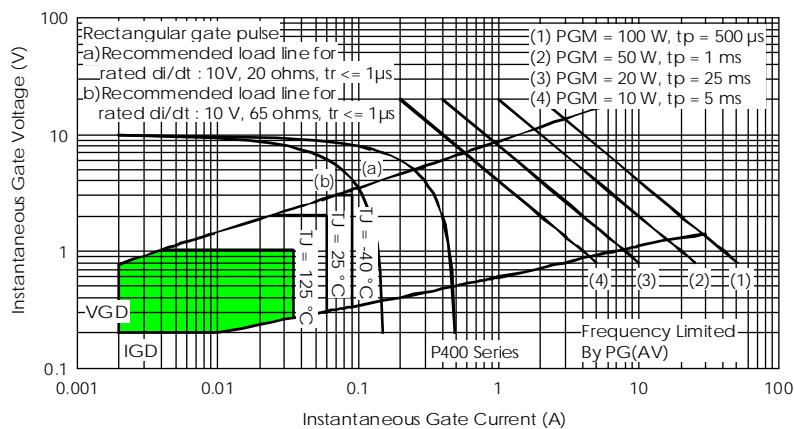


Fig.9-Gate Characteristics